Ultra low capacitance double rail-to-rail ESD protection

Rev. 02 — 19 February 2009

Product data sheet

1. Product profile

1.1 General description

Ultra low capacitance double rail-to-rail ElectroStatic Discharge (ESD) protection devices in leadless ultra small Surface-Mounted Device (SMD) plastic packages.

The devices are designed to protect two Hi-Speed data lines or high-frequency signal lines from the damage caused by ESD and other transients.

PRTR5V0U2F and PRTR5V0U2K integrate two ultra low capacitance rail-to-rail ESD protection channels and one additional ESD protection diode each to ensure signal line protection even if no supply voltage is available.

Table 1.Product overview

| Type number | Package | | Package configuration |
|-------------|---------|--------|-----------------------|
| | NXP | JEDEC | |
| PRTR5V0U2F | SOT886 | MO-252 | leadless ultra small |
| PRTR5V0U2K | SOT891 | - | leadless ultra small |

1.2 Features

- ESD protection of two Hi-Speed data lines or high-frequency signal lines
- Ultra low input/output to ground capacitance: C_(I/O-GND) = 1 pF
- ESD protection up to 8 kV
- IEC 61000-4-2, level 4 (ESD)
- Very low clamping voltage due to an integrated additional ESD protection diode
- Very low reverse current
- AEC-Q101 qualified
- Leadless ultra small SMD plastic packages

1.3 Applications

- USB 2.0 interfaces
- Digital Video Interface (DVI) / High Definition Multimedia Interface (HDMI) interfaces
- Mobile and cordless phones
- Personal Digital Assistants (PDA)
- Digital cameras
- Wide Area Network (WAN) / Local Area Network (LAN) systems
- PCs, notebooks, printers and other PC peripherals



Ultra low capacitance double rail-to-rail ESD protection

1.4 Quick reference data

Quick reference data Table 2.

 $T_{amb} = 25 \circ C$ unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|------------------------|--|--|--------------|-----|-----|------|
| Per channe | el | | | | | |
| C _(I/O-GND) | input/output to ground capacitance | f = 1 MHz; V _(I/O-GND) = 0 V | <u>[1]</u> _ | 1.0 | 1.5 | pF |
| C _(I/O-I/O) | input/output to input/output capacitance | f = 1 MHz; V _(I/O-I/O) = 0 V | [2] _ | 0.6 | - | pF |
| Zener dioc | le | | | | | |
| V _{RWM} | reverse standoff voltage | | [3] _ | - | 5.5 | V |
| C _{sup} | supply pin to ground capacitance | f = 1 MHz; V _{CC} = 0 V | <u>[3]</u> _ | 16 | - | pF |

[1] Measured from pin 1, 3, 4 or 6 to ground.

[2] Measured from pin 1 or 6 to pin 3 or 4.

[3] Measured from pin 5 to ground.

Pinning information 2.

| Table | 3. Pinning | | | |
|-------|-----------------|----------------|--------------------|----------------|
| Pin | Symbol | Description | Simplified outline | Graphic symbol |
| PRTF | R5V0U2F (SOT | ۲886) | | |
| 1 | I/O1 | input/output 1 | | |
| 2 | GND | ground | | |
| 3 | I/O2 | input/output 2 | | <u></u> ₩+₩ |
| 4 | I/O2 | input/output 2 | | |
| 5 | V _{CC} | supply voltage | | |
| 6 | I/O1 | input/output 1 | bottom view | 3 006aab349 |

PRTR5V0U2K (SOT891)

| 1 | I/O1 | input/output 1 | | |
|---|-----------------|----------------|----------------------|--|
| 2 | GND | ground | | |
| 3 | I/O2 | input/output 2 | | |
| 4 | I/O2 | input/output 2 | | |
| 5 | V _{CC} | supply voltage | | |
| 6 | I/O1 | input/output 1 | 6 5 4 bottom view | |

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Ultra low capacitance double rail-to-rail ESD protection

3. Ordering information

| Table 4. Ordering information | | | | | | |
|---------------------------------------|-------|---|---------|--|--|--|
| Type number Package | | | | | | |
| | Name | Description | Version | | | |
| PRTR5V0U2F | XSON6 | plastic extremely thin small outline package; no leads; 6 terminals; body $1 \times 1.45 \times 0.5$ mm | SOT886 | | | |
| PRTR5V0U2K | XSON6 | plastic extremely thin small outline package; no leads; 6 terminals; body $1 \times 1 \times 0.5$ mm | SOT891 | | | |

4. Marking

| Table 5. Marking codes | |
|------------------------|--------------|
| Type number | Marking code |
| PRTR5V0U2F | PF |
| PRTR5V0U2K | РК |

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|---------------------|------------|-----|------|------|
| Per device | | | | | |
| T _{amb} | ambient temperature | | -40 | +85 | °C |
| T _{stg} | storage temperature | | -55 | +125 | °C |

Table 7. ESD maximum ratings

 $T_{amb} = 25 \circ C$ unless otherwise specified.

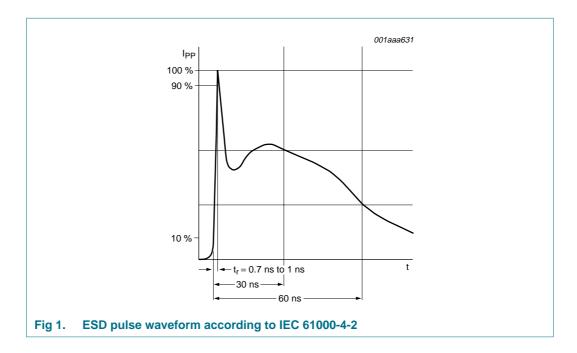
| Symbol | Parameter | Conditions | | Min | Max | Unit |
|-----------|---------------------------------|--------------------------------------|--------|-----|-----|------|
| Per chan | nel | | | | | |
| V_{ESD} | electrostatic discharge voltage | IEC 61000-4-2 (contact discharge) | [1][2] | - | 8 | kV |
| | | MIL-STD-883 (human body model) | [2] | - | 10 | kV |

[1] Device stressed with ten non-repetitive ESD pulses.

[2] Measured from pin 1, 3, 4 or 6 to pin 2 or 5.

Ultra low capacitance double rail-to-rail ESD protection

| Standard | Conditions |
|---|------------------|
| Per channel | |
| IEC 61000-4-2; level 4 (ESD) | > 8 kV (contact) |
| MIL-STD-883; class 3 (human body model) | > 4 kV |



Ultra low capacitance double rail-to-rail ESD protection

6. Characteristics

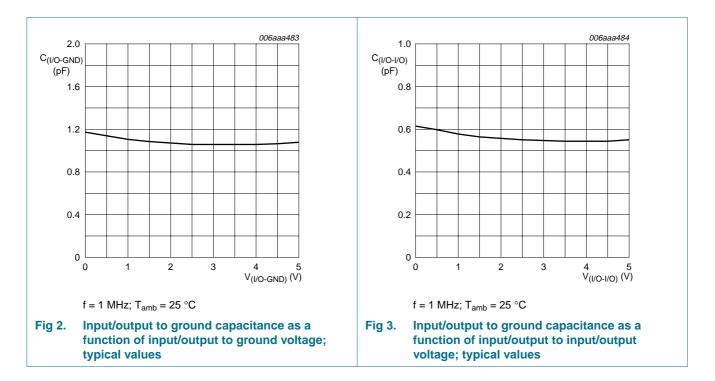
| Symbol | Parameter | Conditions | Min | Тур | Мах | Unit |
|------------------------|--|--|--------------|-----|-----|------|
| Per channe | el l | | | | | |
| I _R | reverse current | $V_R = 5 V$ | <u>[1]</u> - | < 1 | 100 | nA |
| C _(I/O-GND) | input/output to ground capacitance | f = 1 MHz; V _(I/O-GND) = 0 V | <u>[1]</u> - | 1.0 | 1.5 | pF |
| C _(I/O-I/O) | input/output to input/output capacitance | f = 1 MHz; V _(I/O-I/O) = 0 V | [2] _ | 0.6 | - | pF |
| V _F | forward voltage | I _F = 1 mA | [3] _ | 0.7 | - | V |
| Zener diod | e | | | | | |
| V _{RWM} | reverse standoff voltage | | [4] _ | - | 5.5 | V |
| V _{BR} | breakdown voltage | | <u>[4]</u> 6 | - | 9 | V |
| C _{sup} | supply pin to ground capacitance | f = 1 MHz; V _{CC} = 0 V | <u>[4]</u> _ | 16 | - | pF |

[1] Measured from pin 1, 3, 4 or 6 to ground.

[2] Measured from pin 1 or 6 to pin 3 or 4.

[3] Measured from pin 1, 3, 4 or 6 to pin 5.

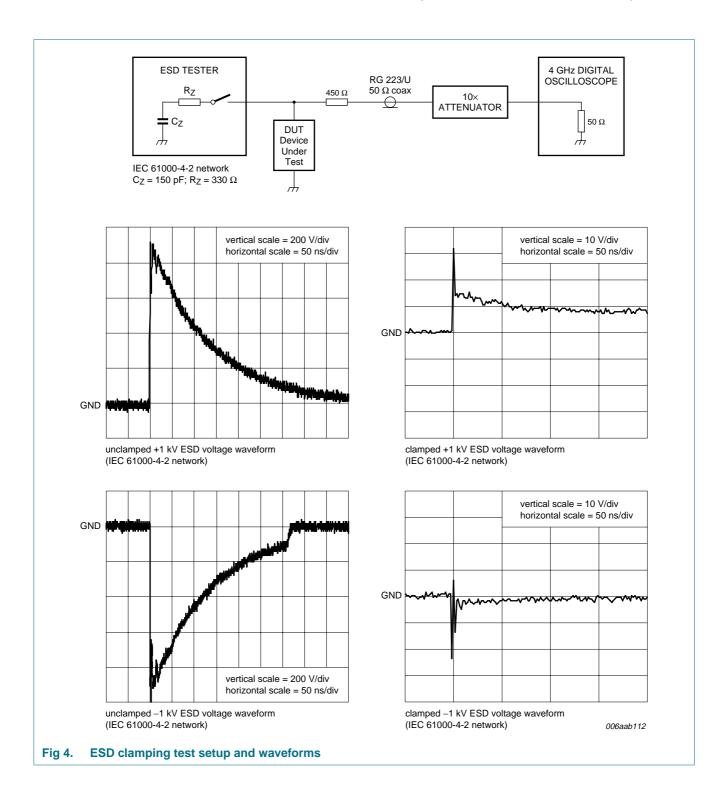
[4] Measured from pin 5 to ground.



NXP Semiconductors

PRTR5V0U2F; PRTR5V0U2K

Ultra low capacitance double rail-to-rail ESD protection



Ultra low capacitance double rail-to-rail ESD protection

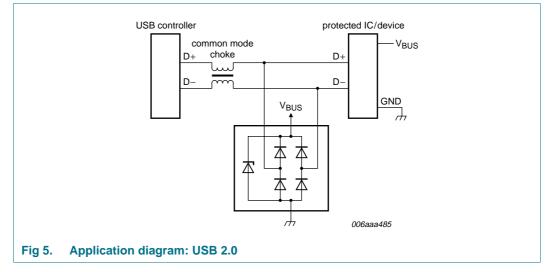
7. Application information

Handling data rates up to 480 Mbit/s, USB 2.0 interfaces require ESD protection devices with an extremely low line capacitance in order to avoid signal distortion.

With a capacitance of only 1 pF, the PRTR5V0U2F and the PRTR5V0U2K offer IEC 61000-4-2, level 4 compliant ESD protection.

PRTR5V0U2F and PRTR5V0U2K integrate two pairs of ultra low capacitance rail-to-rail ESD protection channels and one additional ESD protection diode each.

The additional ESD protection diode connected between ground and V_{CC} prevents charging of the supply.



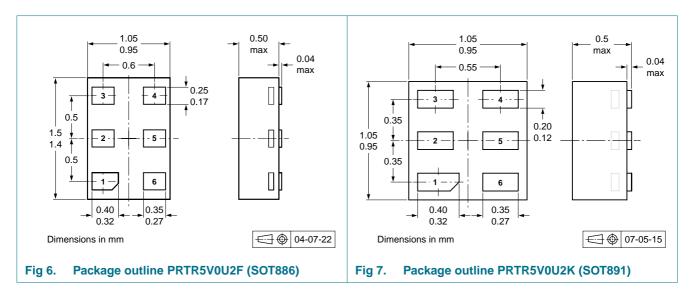
Circuit board layout and protection device placement

Circuit board layout is critical for the suppression of ESD, Electrical Fast Transient (EFT) and surge transients. The following guidelines are recommended:

- 1. Place the PRTR5V0U2F and the PRTR5V0U2K as close to the input terminal or connector as possible.
- 2. The path length between the PRTR5V0U2F or the PRTR5V0U2K and the protected line should be minimized.
- 3. Keep parallel signal paths to a minimum.
- 4. Avoid running protected conductors in parallel with unprotected conductors.
- 5. Minimize all Printed-Circuit Board (PCB) conductive loops including power and ground loops.
- 6. Minimize the length of the transient return path to ground.
- 7. Avoid using shared transient return paths to a common ground point.
- 8. Ground planes should be used whenever possible. For multilayer PCBs, use ground vias.

Ultra low capacitance double rail-to-rail ESD protection

8. Package outline



9. Packing information

Table 10. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

| Type number | Package | Description | ription | |
|-------------|---------|------------------------------------|---------|------|
| | | | | 5000 |
| PRTR5V0U2F | SOT886 | 4 mm pitch, 8 mm tape and reel; T1 | [2] | -115 |
| | | 4 mm pitch, 8 mm tape and reel; T4 | [3] | -132 |
| PRTR5V0U2K | SOT891 | 4 mm pitch, 8 mm tape and reel | | -132 |

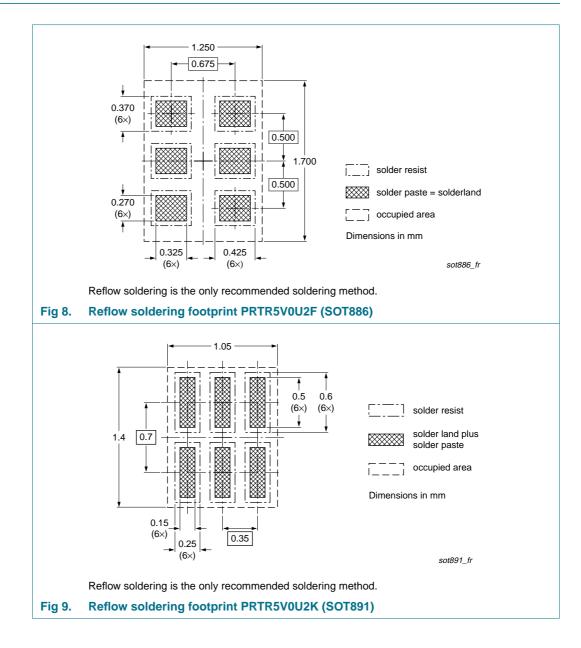
[1] For further information and the availability of packing methods, see Section 13.

[2] T1: normal taping

[3] T4: 90° rotated reverse taping

Ultra low capacitance double rail-to-rail ESD protection

10. Soldering



Ultra low capacitance double rail-to-rail ESD protection

11. Revision history

Table 11.Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|-------------------------|--|-----------------------|---------------|-------------------------|
| PRTR5V0U2F_PRTR5V0U2K_2 | 20090219 | Product data sheet | - | PRTR5V0U2F_PRTR5V0U2K_1 |
| Modifications: | <u>Table 3 "Pi</u> | nning": graphic symbo | ol amended | |
| PRTR5V0U2F_PRTR5V0U2K_1 | 20081106 | Product data sheet | - | - |

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12. Legal information

12.1 Data sheet status

| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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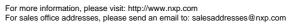
14. Contents

| 1 | Product profile 1 |
|------|---------------------------|
| 1.1 | General description |
| 1.2 | Features |
| 1.3 | Applications 1 |
| 1.4 | Quick reference data |
| 2 | Pinning information 2 |
| 3 | Ordering information 3 |
| 4 | Marking 3 |
| 5 | Limiting values 3 |
| 6 | Characteristics 5 |
| 7 | Application information 7 |
| 8 | Package outline 8 |
| 9 | Packing information |
| 10 | Soldering 9 |
| 11 | Revision history 10 |
| 12 | Legal information 11 |
| 12.1 | Data sheet status 11 |
| 12.2 | Definitions 11 |
| 12.3 | Disclaimers 11 |
| 12.4 | Trademarks 11 |
| 13 | Contact information 11 |
| 14 | Contents 12 |

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